



## PJW3P06A-AU

### 60V P-Channel Enhancement Mode MOSFET

Voltage

-60 V

Current

-3 A

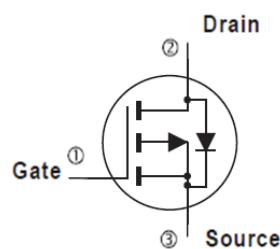
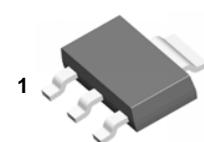
#### Features

- $R_{DS(ON)}$ ,  $V_{GS} @ -10V$ ,  $I_D @ -2A < 170m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS} @ -4.5V$ ,  $I_D @ -1.5A < 220m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### Mechanical Data

- Case : SOT-223 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.043 ounces, 0.123grams

SOT-223



#### Maximum Ratings and Thermal Characteristics ( $T_A = 25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	$V_{DS}$	-60	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	
Continuous Drain Current <sup>(Note 4)</sup>	$I_D$	-3	A
$T_A = 70^\circ C$		-2.4	
Pulsed Drain Current <sup>(Note 1)</sup>	$I_{DM}$	-12	
Power Dissipation	$P_D$	3.1	W
$T_A = 70^\circ C$		2	
Single Pulse Avalanche Energy <sup>(Note 6)</sup>	$E_{AS}$	32	mJ
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55~150	°C
Typical Thermal Resistance - Junction to Ambient <sup>(Note 4,5)</sup>	$R_{\theta JA}$	40.3	°C/W

- Limited only By Maximum Junction Temperature



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## Electrical Characteristics ( $T_A=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-60	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	-1	-1.88	-2.5	
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_D=2A$	-	140	170	$m\Omega$
		$V_{GS}=-4.5V, I_D=1.5A$	-	190	220	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=-60V, V_{GS}=0V$	-	-	-1	$\mu A$
Gate-Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	$\pm 100$	$nA$
<b>Dynamic</b> <small>(Note 7)</small>						
Total Gate Charge	$Q_g$	$V_{DS}=-30V, I_D=-2A,$ $V_{GS}=-10V$ <small>(Note 2,3)</small>	-	8.3	-	$nC$
Gate-Source Charge	$Q_{gs}$		-	1.8	-	
Gate-Drain Charge	$Q_{gd}$		-	1.6	-	
Input Capacitance	$C_{iss}$	$V_{DS}=-30V, V_{GS}=0V,$ $f=1MHz$	-	430	-	$pF$
Output Capacitance	$C_{oss}$		-	33	-	
Reverse Transfer Capacitance	$C_{rss}$		-	29	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=-30V, I_D=-1A,$ $V_{GS}=-10V,$ $R_G=6\Omega$ <small>(Note 2,3)</small>	-	5.1	-	$ns$
Turn-On Rise Time	$t_r$		-	20	-	
Turn-Off Delay Time	$t_{d(off)}$		-	36	-	
Turn-Off Fall Time	$t_f$		-	11	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_S$	---	-	-	-2	A
Diode Forward Voltage	$V_{SD}$	$I_S=-1A, V_{GS}=0V$	-	-0.78	-1	V

### NOTES :

1. Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature  $T_{J(MAX)}=150^\circ C$ . Ratings are based on low frequency and duty cycles to keep initial  $T_J = 25^\circ C$ .
4. The maximum current rating is package limited.
5.  $R_{OJA}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
6. The test condition is  $L=1mH, I_{AS}=-8A, V_{DD}=-25V, V_{GS}=-10V$
7. Guaranteed by design, not subject to production testing.



# PJW3P06A-AU

## TYPICAL CHARACTERISTIC CURVES

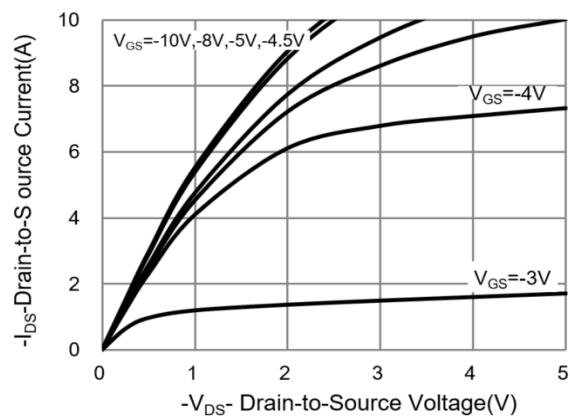


Fig.1 Output Characteristics

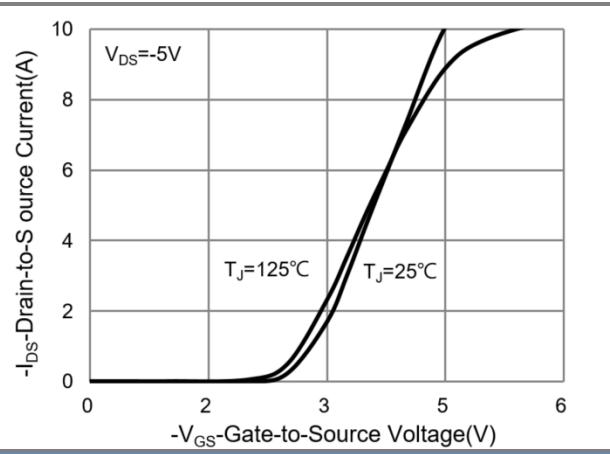


Fig.2 Transfer Characteristics

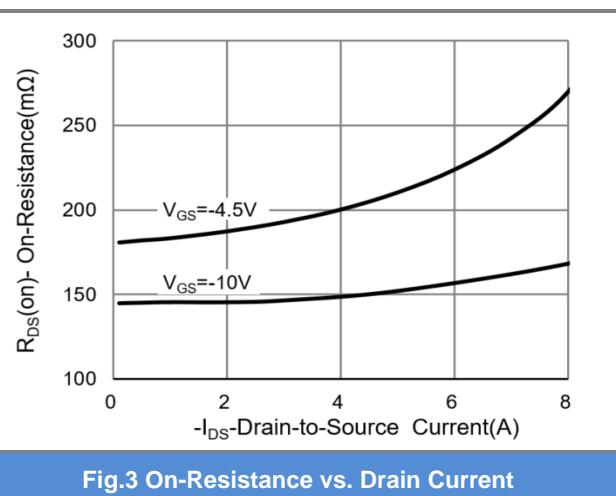


Fig.3 On-Resistance vs. Drain Current

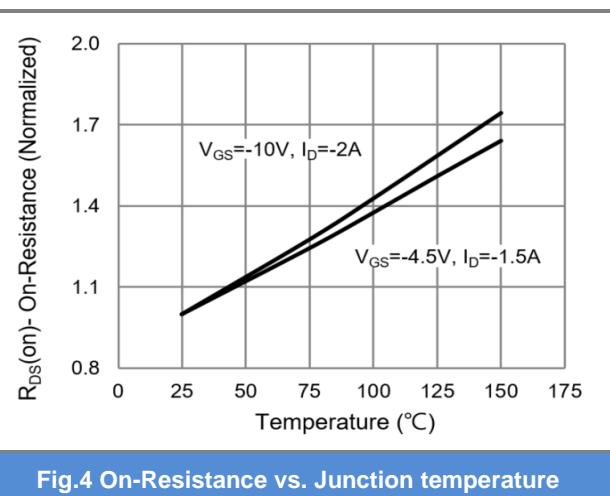


Fig.4 On-Resistance vs. Junction temperature

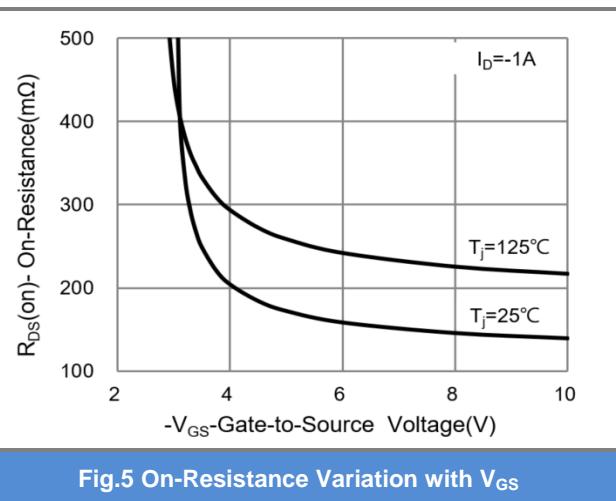


Fig.5 On-Resistance Variation with  $V_{GS}$

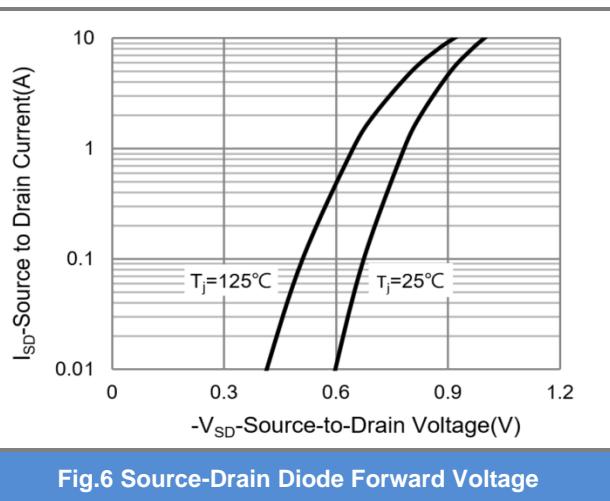


Fig.6 Source-Drain Diode Forward Voltage



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## TYPICAL CHARACTERISTIC CURVES

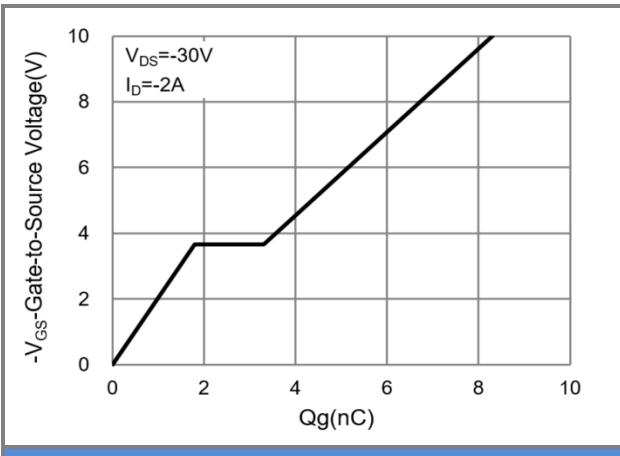


Fig.7 Gate-Charge Characteristics

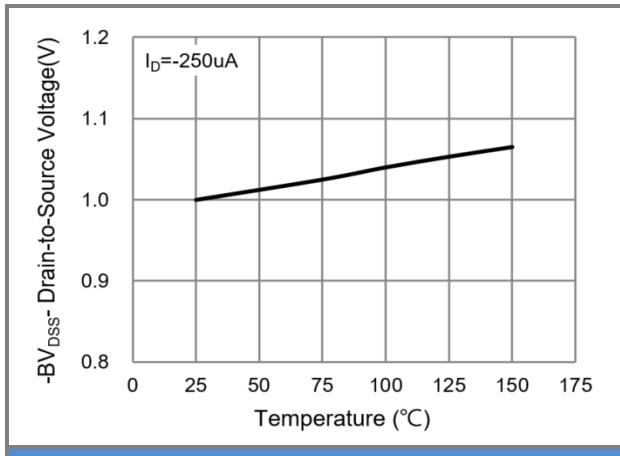


Fig.8 Breakdown Voltage Variation vs. Temperature

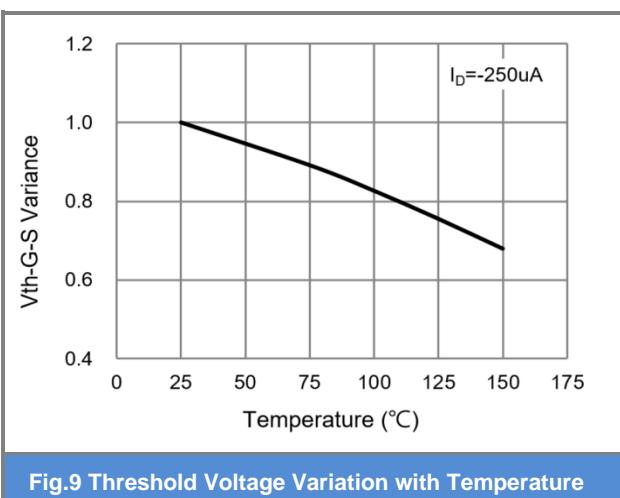


Fig.9 Threshold Voltage Variation with Temperature

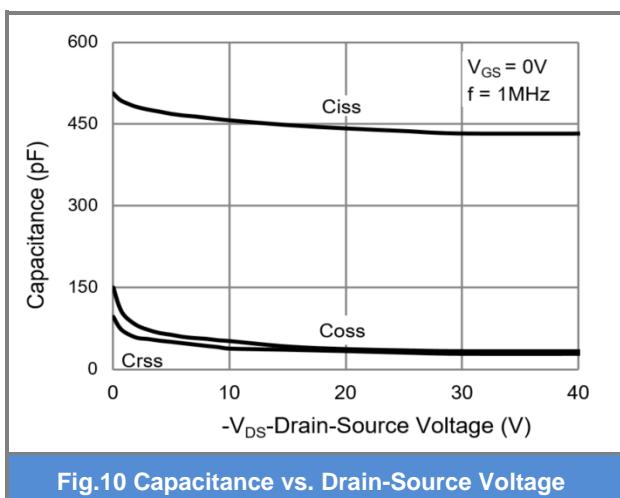


Fig.10 Capacitance vs. Drain-Source Voltage

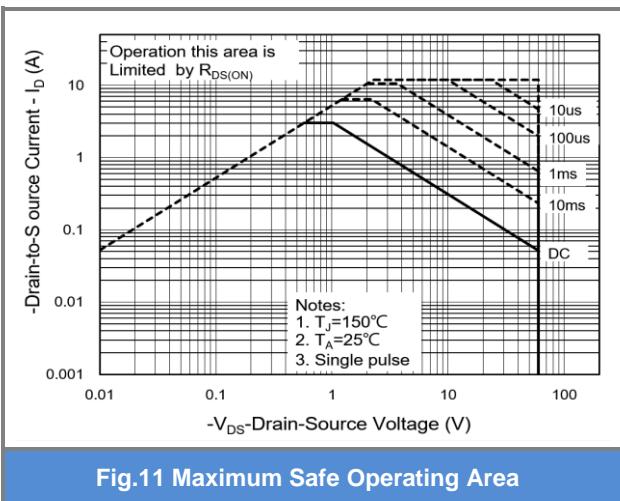


Fig.11 Maximum Safe Operating Area

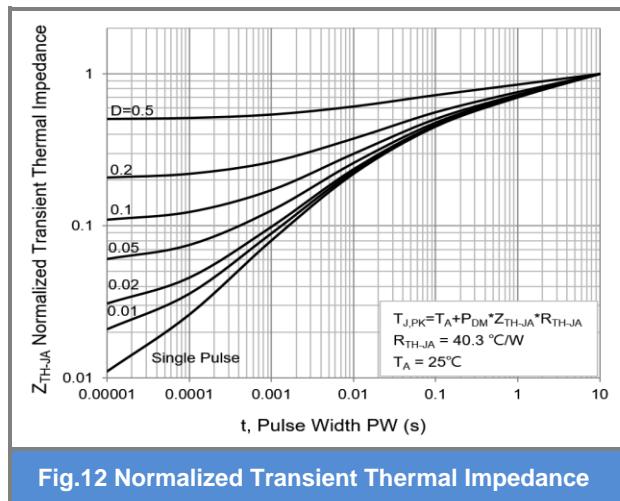


Fig.12 Normalized Transient Thermal Impedance

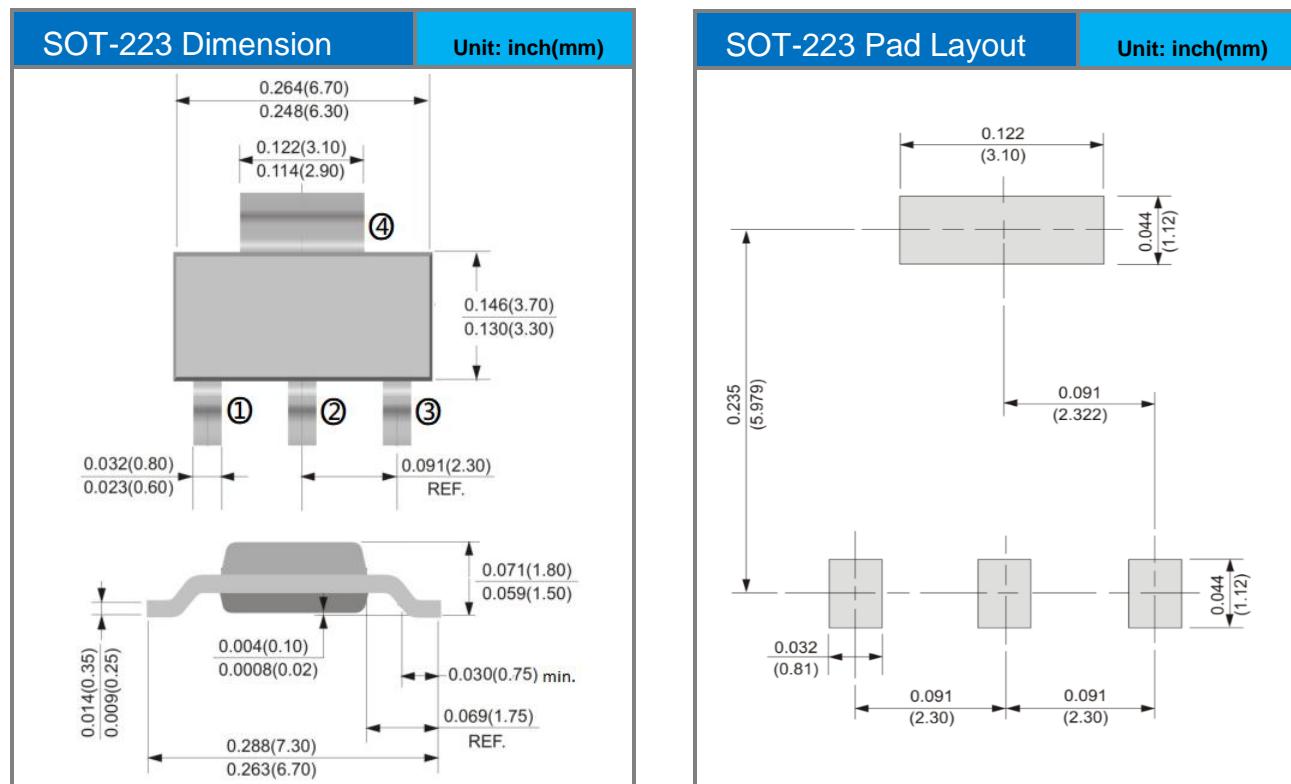


## PJW3P06A-AU

### Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJW3P06A-AU_R2_000A1	SOT-223	2,500pcs / 13" reel	W3P06A	Halogen free

### Packaging Information & Mounting Pad Layout





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